

## *Erratum*

# All the physical and electrical parameters of the MOS transistor on a single graph ( $Q\Psi$ )

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In Section Conclusion (p. 158), the first equation should read:

$$I = \mu_n \frac{W}{L} \frac{\varepsilon_{ox}}{e_{ox}} \left[ \left( V_G - 2\psi_b - \frac{V_D}{2} \right) V_D - \frac{2}{3} \frac{\sqrt{2\varepsilon_{SC}qN_a}}{\frac{\varepsilon_{ox}}{e_{ox}}} \left\{ (V_D + 2\psi_b + |V_{sub}|)^{\frac{3}{2}} - (2\psi_b + |V_{sub}|)^{\frac{3}{2}} \right\} \right].$$

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